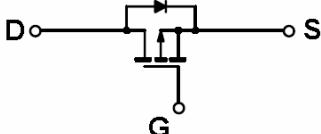


## 20V P-Channel Enhancement Mode MOSFET

 <b>SOT-23</b>	Pin assignment: 1. Gate 2. Source 3. Drain	<b>V<sub>DS</sub> = - 20V</b> <b>R<sub>DS(on)</sub>, V<sub>GS</sub> @ - 4.5V, I<sub>DS</sub> @ - 2.8A = 130mΩ</b> <b>R<sub>DS(on)</sub>, V<sub>GS</sub> @ - 2.5V, I<sub>DS</sub> @ - 2.0A = 190mΩ</b>						
<b>Features</b>		<ul style="list-style-type: none"> <li>◊ Advanced trench process technology</li> <li>◊ High density cell design for ultra low on-resistance</li> <li>◊ Excellent thermal and electrical capabilities</li> <li>◊ Compact and low profile SOT-23 package</li> </ul>						
<b>Block Diagram</b>		 <b>Ordering Information</b> <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="text-align: center;">Part No.</th><th style="text-align: center;">Packing</th><th style="text-align: center;">Package</th></tr> </thead> <tbody> <tr> <td style="text-align: center;">RTM2301CX</td><td style="text-align: center;">Tape &amp; Reel</td><td style="text-align: center;">SOT-23</td></tr> </tbody> </table>	Part No.	Packing	Package	RTM2301CX	Tape & Reel	SOT-23
Part No.	Packing	Package						
RTM2301CX	Tape & Reel	SOT-23						
<b>Absolute Maximum Rating</b> (Ta = 25 °C unless otherwise noted)								
Parameter	Symbol	Limit	Unit					
Drain-Source Voltage	V <sub>DS</sub>	- 20V	V					
Gate-Source Voltage	V <sub>GS</sub>	± 8	V					
Continuous Drain Current	I <sub>D</sub>	- 2.3	A					
Pulsed Drain Current	I <sub>DM</sub>	- 10	A					
Maximum Power Dissipation	Ta = 25 °C	P <sub>D</sub>	1.25	W				
	Ta = 75 °C		0.8					
Operating Junction Temperature	T <sub>J</sub>	+150	°C					
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C					
<b>Thermal Performance</b>								
Parameter	Symbol	Limit	Unit					
Lead Temperature (1/8" from case)	T <sub>L</sub>	5	S					
Junction to Ambient Thermal Resistance (PCB mounted)	R <sub>θja</sub>	100	°C/W					

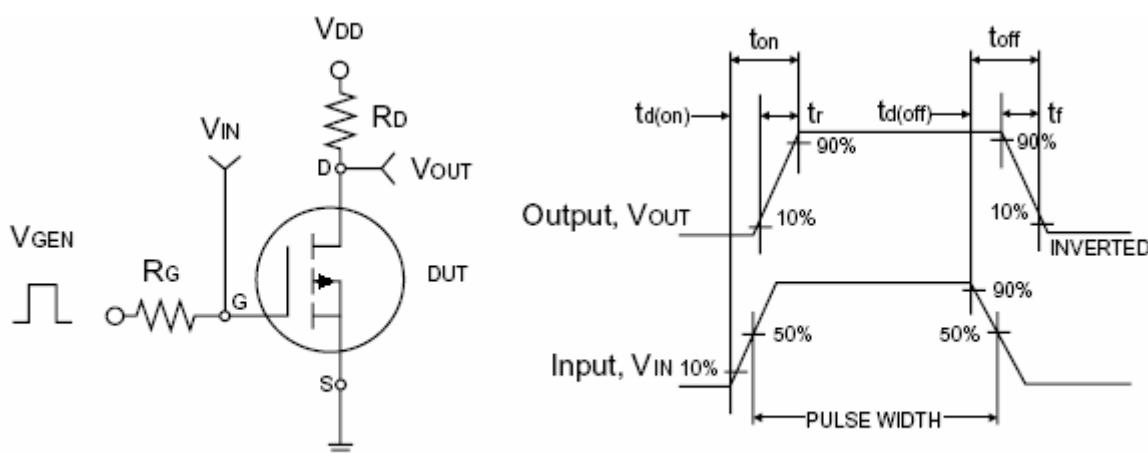
Note: Surface mounted on FR4 board t<=5sec.

## Electrical Characteristics

T<sub>a</sub> = 25 °C, unless otherwise noted

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = - 250uA	BV <sub>DSS</sub>	- 20	--	--	V
Drain-Source On-State Resistance	V <sub>GS</sub> = - 4.5V, I <sub>D</sub> = - 2.8A	R <sub>DS(ON)</sub>	--	95	130	mΩ
Drain-Source On-State Resistance		R <sub>DS(ON)</sub>	--	122	190	
Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = - 250uA	V <sub>GS(TH)</sub>	- 0.45	--	--	V
Zero Gate Voltage Drain Current	V <sub>DS</sub> = - 16V, V <sub>GS</sub> = 0V	I <sub>DSS</sub>	--	--	- 1.0	uA
Gate Body Leakage	V <sub>GS</sub> = ± 8V, V <sub>DS</sub> = 0V	I <sub>GSS</sub>	--	--	± 100	nA
On-State Drain Current	V <sub>DS</sub> ≥ - 10V, V <sub>GS</sub> = - 5V	I <sub>D(ON)</sub>	- 6	--	--	A
Forward Transconductance	V <sub>DS</sub> = - 5V, I <sub>D</sub> = - 2.8A	g <sub>fs</sub>	--	6.5	--	S
<b>Dynamic</b>						
Total Gate Charge	V <sub>DS</sub> = - 6V, I <sub>D</sub> = - 2.8A, V <sub>GS</sub> = - 4.5V	Q <sub>g</sub>	--	5.4	10	nC
Gate-Source Charge		Q <sub>gs</sub>	--	0.8	--	
Gate-Drain Charge		Q <sub>gd</sub>	--	1.1	--	
Turn-On Delay Time	V <sub>DD</sub> = - 6V, R <sub>L</sub> = 6Ω, I <sub>D</sub> = - 1A, V <sub>GEN</sub> = - 4.5V, R <sub>G</sub> = 6Ω	t <sub>d(on)</sub>	--	5	25	nS
Turn-On Rise Time		t <sub>r</sub>	--	19	60	
Turn-Off Delay Time		t <sub>d(off)</sub>	--	95	110	
Turn-Off Fall Time		t <sub>f</sub>	--	65	80	
Input Capacitance	V <sub>DS</sub> = - 6V, V <sub>GS</sub> = 0V, f = 1.0MHz	C <sub>iss</sub>	--	447	--	pF
Output Capacitance		C <sub>oss</sub>	--	127	--	
Reverse Transfer Capacitance		C <sub>rss</sub>	--	80	--	
<b>Source-Drain Diode</b>						
Max. Diode Forward Current		I <sub>S</sub>	--	--	- 1.6	A
Diode Forward Voltage	I <sub>S</sub> = - 1.6A, V <sub>GS</sub> = 0V	V <sub>SD</sub>	--	- 0.8	- 1.2	V

Note : pulse test: pulse width <=300uS, duty cycle <=2%

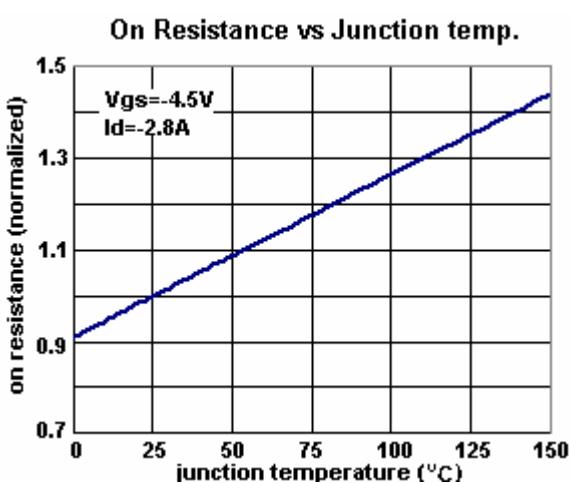
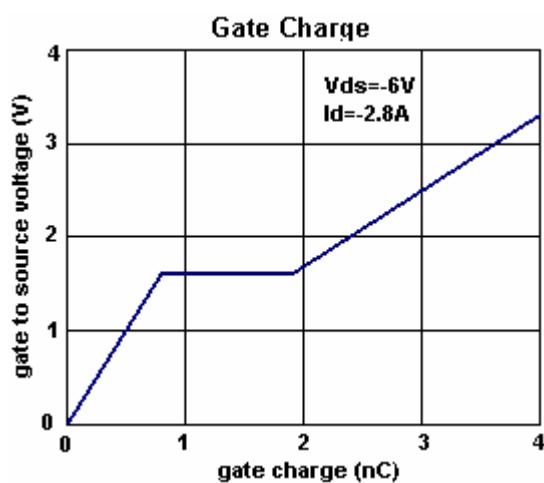
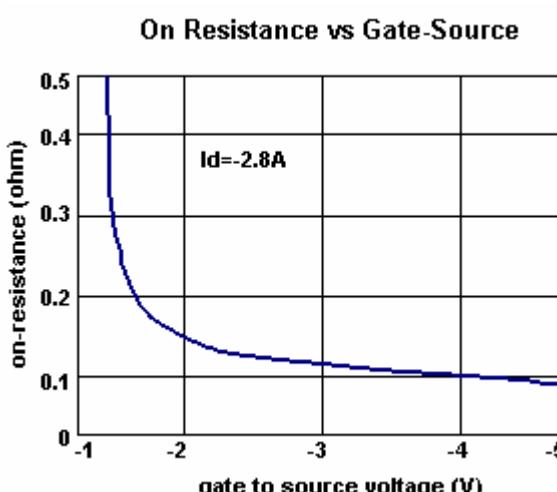
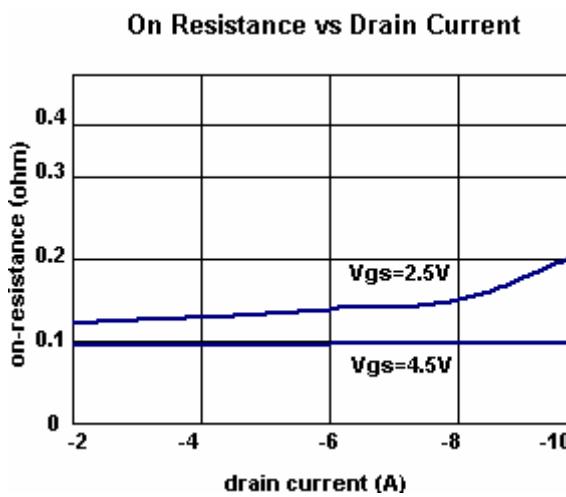
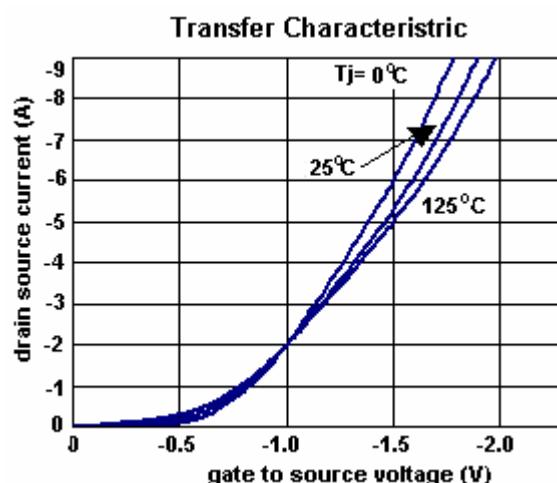
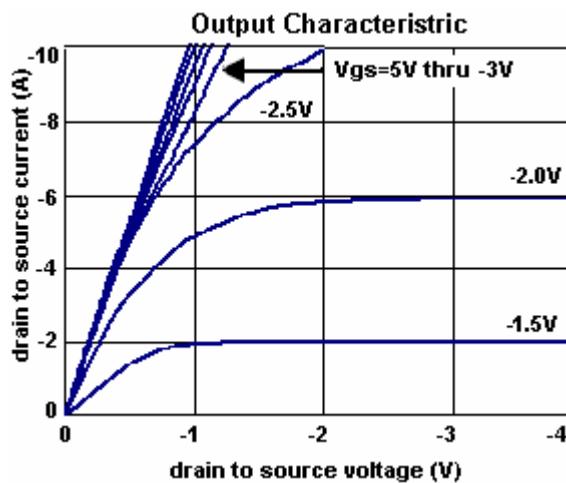


Switching Test Circuit

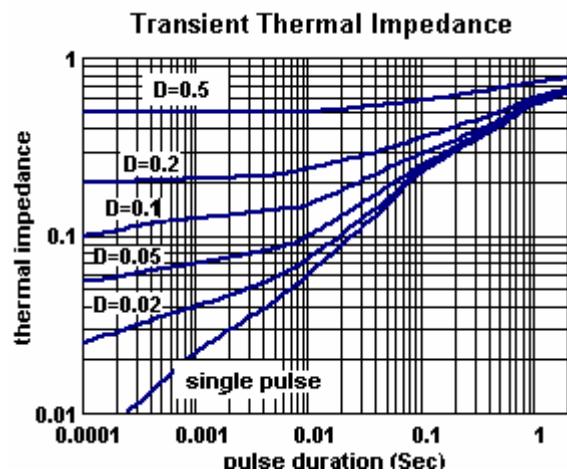
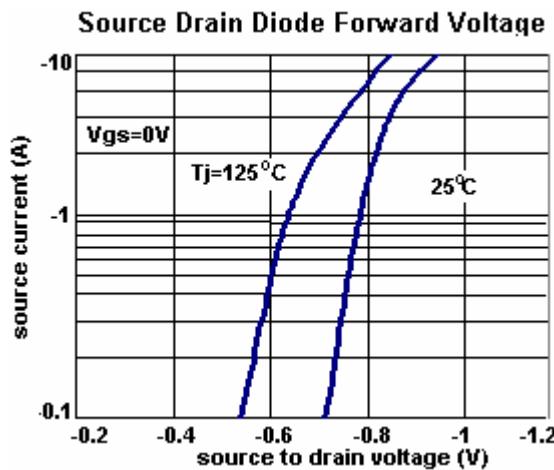
Switchin Waveforms

## RTM2301

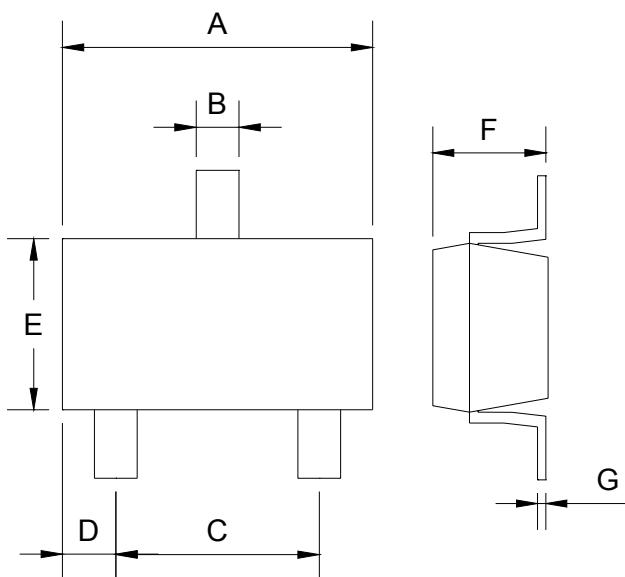
Typical Characteristics Curve ( $T_a = 25^\circ\text{C}$  unless otherwise noted)



**Typical Characteristics Curve** ( $T_a = 25^\circ\text{C}$  unless otherwise noted)



SOT-23 Mechanical Drawing



SOT-23 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.88	2.91	0.113	0.115
B	0.39	0.42	0.015	0.017
C	1.78	2.03	0.070	0.080
D	0.51	0.61	0.020	0.024
E	1.59	1.66	0.063	0.065
F	1.04	1.08	0.041	0.043
G	0.07	0.09	0.003	0.004